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### Complete 5µs CMOS 10-Bit A/D Converter

### **General Description**

The MAX173 is a complete, 10-bit linear analog-to-digital converter (ADC) that combines high speed, low power consumption, and an on-chip voltage reference. The conversion time is  $5\mu$ s. The buried zener reference provides low drift and low noise performance.

External component requirements are limited to only decoupling capacitors for the power supply and refer-ence voltages. On-chip clock circuitry is also included which can either be driven from an external source, or in stand-alone applications, from a crystal.

The MAX173 uses a standard microprocessor interface architecture. Three-state data\_outputs are controlled by Read (RD) and Chip Select (CS) inputs. Data access and bus release times of 90ns and 75ns respectively ensure compatibility with most popular microproces-sors without resorting to wait states.

### Applications

- Digital Signal Processing (DSP)
- High Accuracy Process Control
- High Speed Data Acquisition
- Electro-Mechanical Systems

### AGND VRE 3 2.5kΩ 字 12-BIT DAD 荃 REFERENCE SUCCESSIVE Approximation Register MAX173 12-BIT LATCH 22 BUSY 21 ČS 20 RD в CONTROL Logic 19\_ HBEN MULTIPLEXER THREE STATE OUTPUT DRIVERS 18 - CLK OUT THREE-STATE CLOCK OSCILLATOR 17 CLK IN OUTPUT Drivers 1 12 13 16 03/11 00/8 DGND 8 11

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### **Functional Diagram**



- 5μs Conversion Time
- On-Chip ±40ppm/°C Voltage Reference
- 90ns Access Time
- 215mW (Max) Power Consumption
- ♦ 24-Lead Narrow DIP and Wide SO Packages

### **Ordering Information**

PART	TEMP. RANGE	PACKAGE*			
MAX173CNG	0°C to +70°C	Plastic DIP			
MAX173CWG	0°C to +70°C	Wide SO			
MAX173C/D	0°C to +70°C	Dice**			
MAX173ENG	-40° C to +85° C	Plastic DIP			
MAX173EWG	-40°C to +85°C	Wide SO			
MAX173MRG	-55°C to +125°C	CERDIP			

\*\* Consult factory for dice specifications.

### Pin Configurations



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# **MAX173**

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### ABSOLUTE MAXIMUM RATINGS

**MAX173** 

V <sub>DD</sub> to DGND -0.3V to +7V   V <sub>SS</sub> to DGND +0.3V to -17V   AGND to DGND -0.3V, V <sub>DD</sub> + 0.3V   AIN to AGND -15V to +15V   Digital Input Voltage to DGND -0.3V, V <sub>DD</sub> + 0.3V
(Pins 17, 19-21) Digital Output Voltage to DGND0.3V, V <sub>DD</sub> + 0.3V (Pins 4-11, 13-16, 18, 22)

Operating Temperature Ranges	
MAX173XC	С
MAX173XE	С
MAX173XM55°C to +125°	С
Storage Temperature Range65°C to +160°	С
Power Dissipation (any Package) to +75°C 1000m	W
Derates Above +75°C by 10mW/°	С
Lead Temperature (Soldering 10 seconds) +300°	С

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**ELECTRICAL CHARACTERISTICS** ( $V_{DD}$  = +5V ± 5%,  $V_{SS}$  = -12V or -15V ± 5%; Slow Memory Mode;  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$  unless otherwise noted,  $f_{CLK}$  = 2.5MHz.)

PARAMETER	SYMBOL	CONDITIC	MIN	TYP	MAX	UNITS	
ACCURACY	· · · · · · · · · · · · · · · · · · ·						
Resolution		-		12			Bits
No Missing Code Resolution				10			Bits
Integral Non-Linearity	INL				_	±0.05	%FSR
Offset Error (Note 1)						±5	mV
Full Scale Error (Note 2)						±0.4	%
Full Scale Tempco (Notes 3, 4)						±45	ppm/°C
ANALOG INPUT				_			
Input Voltage Range				0		5	V
Input Current		AIN = 0V to +5V			3.5	mA	
INTERNAL REFERENCE							
V <sub>REF</sub> Output Voltage		T <sub>A</sub> = 25° C		-5.2	-5.25	-5.3	V
VREF Output Tempco (Note 5)				±40		ppm/°C	
Output Current Sink Capability		(Note 6)				5	mA
LOGIC INPUTS							
Input Low Voltage	VIL	ČŠ, RD, HBEN, CLKIN				0.8	V
Input High Voltage	VIH	CS, RD, HBEN, CLKIN					V
Input Capacitance (Note 7)	CIN	CS RD, HBEN, CLKIN				10	pF
Input Current	1 <sub>IN</sub>	ČŠ, RD, HBEN CLKIN	VIN = 0 to V <sub>DD</sub>			±10 ±20	μA
LOGIC OUTPUTS							
Output Low Voltage	V <sub>OL</sub>	D11-D0/8, BUSY, CLKOU	Г I <sub>SINK</sub> = 1.6 mA			0.4	V
Output High Voltage	V <sub>OH</sub>	D11-D0/8, BUSY, CLKOU	4			V	
Floating State Leakage Current	ILKG	D11-D0/8, V <sub>OUT</sub> = 0V to V			±10	μΑ	
Floating State Output Capacitance (Note 7)	COUT				15	pF	
CONVERSION TIME	•	· · · · · · · · · · · · · · · · · · ·					
MAX173	t <sub>CONV</sub>	Synchronous (12.5 clock cycles) Asynchronous (12 to 13 clock cycles)		4.8		5 5.2	μs

2 \_\_\_\_\_

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### ELECTRICAL CHARACTERISTICS (continued)

PARAMETER	PARAMETER SYMBOL CONDITIONS			TYP	МАХ	UNITS	
POWER SUPPLY REJECTIO	N					•	
V <sub>DD</sub> Only		FS Change, V <sub>SS</sub> = -15V, V <sub>DD</sub> = 4.75V to 5.25V		%			
V <sub>SS</sub> Only		FS Change, V <sub>DD</sub> = 5V, V <sub>SS</sub> = -5% to +5% ±0.01					
POWER REQUIREMENTS		••••••				•	
V <sub>DD</sub>		±5% for Specified Performance		5		V	
V <sub>SS</sub> (Note 8)		±5% for Specified Performance		-12 or -15	5	V	
I <sub>DD</sub>		CS = RD = V <sub>DD</sub> , AIN = 5V		5	7	mA	
I <sub>SS</sub>		$\overline{\text{CS}} = \overline{\text{RD}} = V_{\text{DD}}, \text{AIN} = 5V$		8	12	mA	
Power Dissipation		V <sub>DD</sub> = +5V, V <sub>SS</sub> = -15V		145	215	mW	

Note 1: Typical change over temp is  $\pm 1.2$ mV. Note 2:  $V_{DD} = +5V$ ,  $V_{SS} = -15V$ , FS = +5.000V. Ideal last code transition = FS - 1.8mV. Note 3: Full Scale TC =  $\Delta$ FS/ $\Delta$ T, where  $\Delta$ FS is full scale change from T<sub>A</sub> =  $25^{\circ}$ C to T<sub>MIN</sub> or T<sub>MAX</sub>.

Note 4: Includes internal reference drift.

Note 5:  $V_{REF} TC = \Delta V_{REF}/\Delta T$ , where  $\Delta V_{REF}$  is reference voltage change from  $T_A = 25^{\circ}C$  to  $T_{MIN}$  or  $T_{MAX}$ . Note 6: Output current should not change during conversion. Note 7: Guaranteed by design, not subject to test. Note 8: Functional operation at  $V_{SS} = -12V \pm 5\%$  is guaranteed by testing offset error and full scale error.

TIMING CHARACTERISTICS (Note 9) (See MAX162 data sheet for  $t_1-t_{10}$  description) ( $V_{DD} = +5V$ ,  $V_{SS} = -12V$  or -15V;  $T_A = T_{MIN}$  to  $T_{MAX}$ , specifications in bold type are 100% tested, others are guaranteed by design, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	T <sub>A</sub> = 25° C		MAX173C/E		MAX173M			
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
CS to RD Setup Time	t <sub>1</sub>		0			0		0		ns
RD to BUSY Delay (Note 12)	t <sub>2</sub>	C <sub>L</sub> = 50pF		90	190		230		270	ns
Data Access Time (Note 10)	t <sub>3</sub>	C <sub>L</sub> = 20pF		60	90		110		120	ns
Data Access Time (Notes 10, 12)	t <sub>3</sub>	C <sub>L</sub> = 100pF		70	125		150		170	ns
RD Pulse Width	t4		t <sub>3</sub>			t <sub>3</sub>		t <sub>3</sub>		
CS to RD Hold Time	t <sub>5</sub>		0			0		0		ns
Data Setup Time After BUSY (Notes 10, 12)	t <sub>6</sub>				80		105		120	ns
Bus Relinquish Time (Notes 11, 12)	t <sub>7</sub>				75		85		90	ns
HBEN to RD Setup Time	t <sub>8</sub>		0			0	_	0		ns
HBEN to RD Hold Time	t9		0			0		0		ns
Delay Between Read Operations	t <sub>10</sub>		200			200		200		ns

Note 9: All input control signals are specified with  $t_f = t_r \approx 5ns (10\% \text{ to } 90\% \text{ of } +5V)$  and timed from a voltage level of +1.6V. Note 10:  $t_3$  and  $t_6$  are measured with the load circuits of Figure 1 (see MAX162 data sheet) and defined as the time required for an output to cross 0.8V or 2.4V.

Note 11: t7 is defined as the time required for the data lines to change 0.5V when loaded with the circuits of Figure 2 (see MAX162 data sheet)

Note 12: This specification is 100% production tested.

### For additional information on using the MAX173 please refer to MAX162 data sheet.

**MAX173** 

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4 ---

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